The RF Line

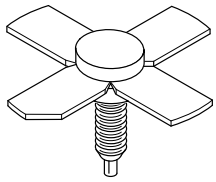
NPN Silicon RF Power Transistor

. . . designed for 12.5 Volt UHF large–signal amplifier applications in industrial and commercial FM equipment operating to 512 MHz.

- Specified 12.5 Volt, 512 MHz Characteristics
  Output Power = 15 W
  Minimum Gain = 7.8 dB
  Efficiency = 55%
- Built–In Matching Network for Broadband Operation
- Gold Metallized, Emitter Ballasted for Long Life and Reliability
- Capable of 20:1 VSWR Load Mismatch at 15.5 V Supply Voltage
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

MRF654

**15 W, 470 MHz
RF POWER
TRANSISTOR
NPN SILICON**



CASE 244–04, STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	16	Vdc
Collector–Base Voltage	V_{CBO}	36	Vdc
Emitter–Base Voltage	V_{EBO}	4.0	Vdc
Collector Current — Continuous	I_C	4.0	Adc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	44 0.25	Watts W/°C
Storage Temperature Range	T_{stg}	–65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	4.0	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

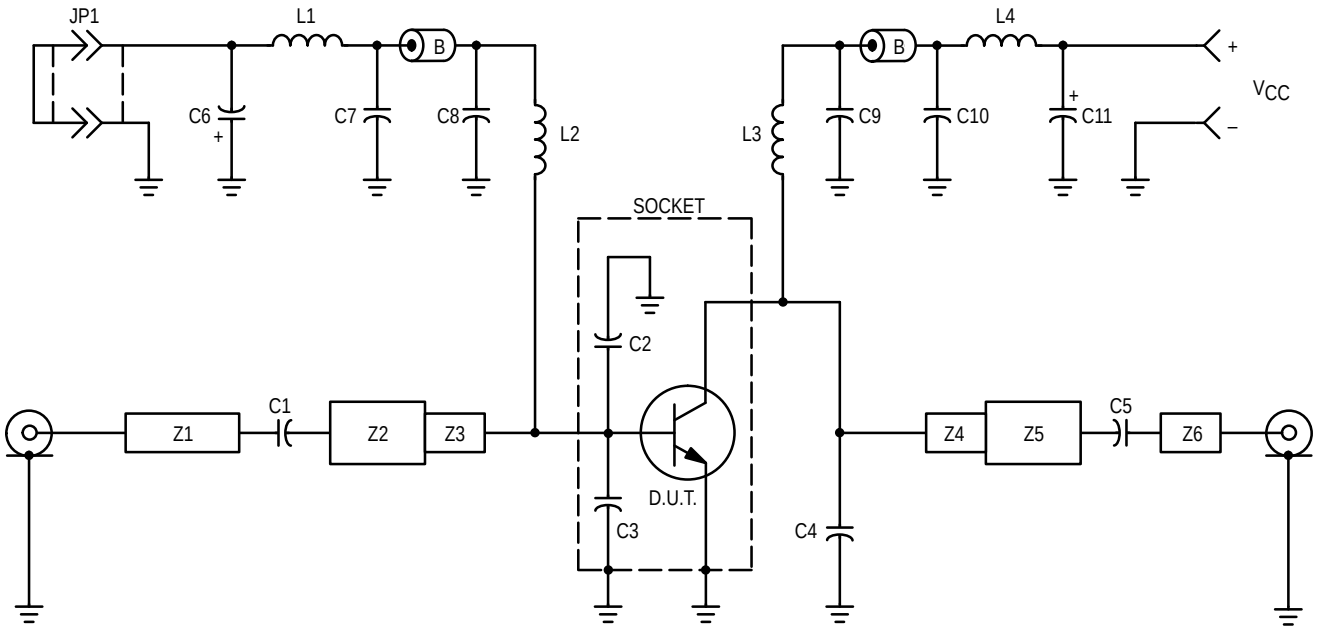
Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I_C = 25 mAdc, I_B = 0)	$V_{(BR)CEO}$	16	—	—	Vdc
Collector–Emitter Breakdown Voltage (I_C = 25 mAdc, V_{BE} = 0)	$V_{(BR)CES}$	36	—	—	Vdc
Emitter–Base Breakdown Voltage (I_E = 5.0 mAdc, I_C = 0)	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector–Cutoff Current (V_{CE} = 15 Vdc, V_{BE} = 0)	I_{CES}	—	—	2.0	mAdc

(continued)

© Motorola, Inc. 1994

ELECTRICAL CHARACTERISTICS — continued (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
DC Current Gain (I_C = 1.0 Adc, V_{CE} = 5.0 Vdc)	h_{FE}	20	—	120	—
DYNAMIC CHARACTERISTICS					
Output Capacitance (V_{CB} = 15 Vdc, I_E = 0, f = 1.0 MHz)	C_{ob}	—	31	45	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Power Gain (V_{CC} = 12.5 Vdc, P_{out} = 15 W, f = 512 MHz)	G_{pe}	7.8	8.8	—	dB
Collector Efficiency (V_{CC} = 12.5 Vdc, P_{out} = 15 W, f = 512 MHz)	η	55	63	—	%
Load Mismatch Stress (V_{CC} = 15.5 Vdc, f = 512 MHz, P_{in} = 3.0 W, VSWR = 20:1, All Phase Angles)	ψ	No Degradation in Output Power			



C1, C5 — 68 pF Mini–Unelco
C2, C3 — 33 pF, Mini–Unelco
C4 — 47 pF, Mini–Unelco
C6, C11 — 10 μF, 25 V Tantalum
C7, C10 — 0.1 μF, Ceramic
C8, C9 — 91 pF, Mini–Unelco
L1, L4 — 4–1/2 Turns, #18 AWG, Enamel Covered, 0.16″ ID
L2, L3 — 2 Turns, #18 AWG Enamel Covered, 0.16″ ID
B — Ferrite Bead, Ferroxcube 56–590–65–3B
Z1–Z6 — See PCB Artwork
PCB — 1/32″ G–10, ε_r = 4.5 @ UHF
Socket — See Socket Drawings
JP1 — Jumper, #14 AWG w/Banana Plugs

Figure 1. 440–512 MHz Broadband Test Circuit

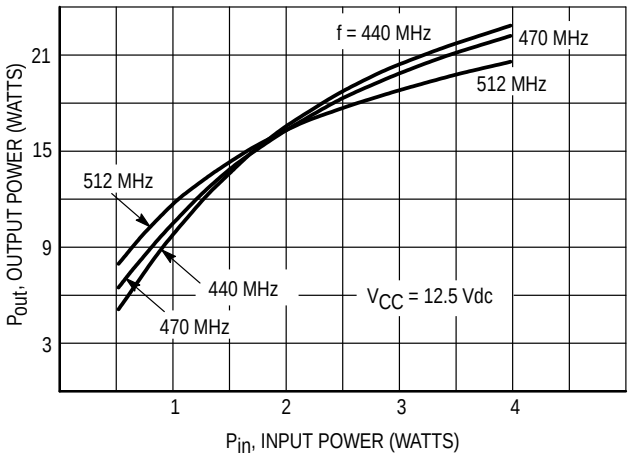


Figure 2. Output Power versus Input Power

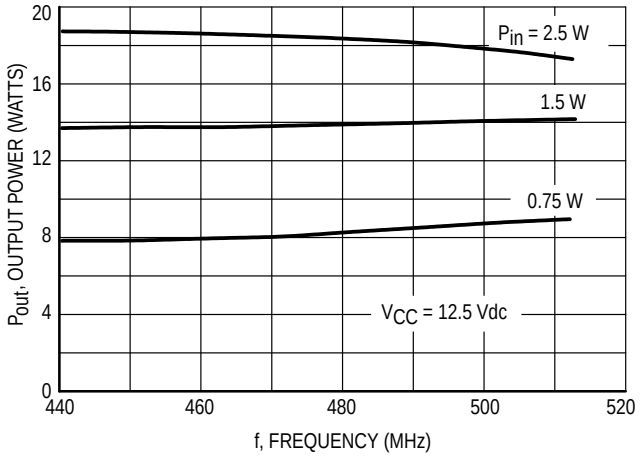


Figure 3. Output Power versus Frequency

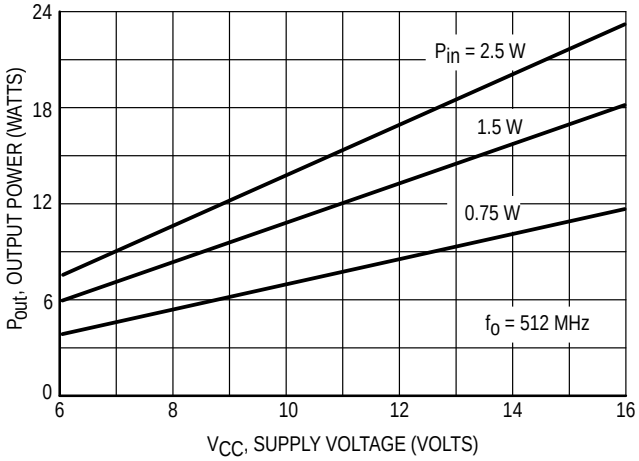


Figure 4. Power Output versus Supply Voltage

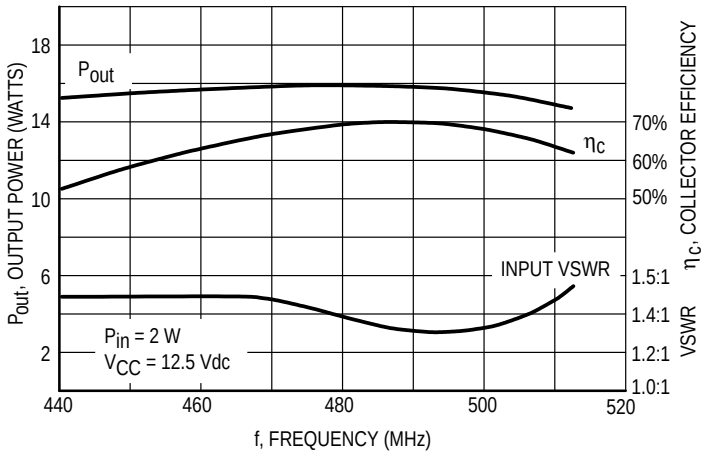
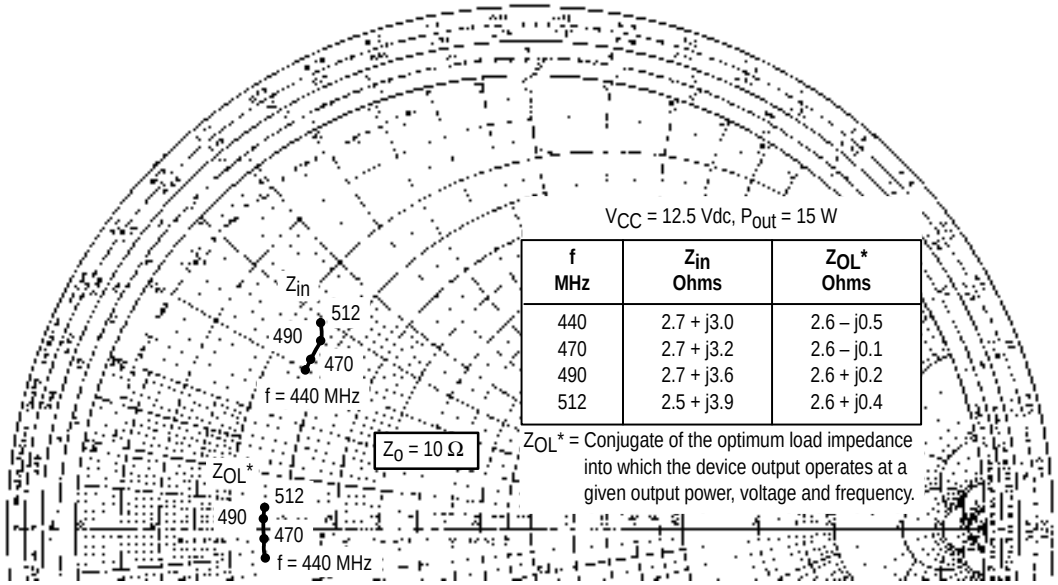


Figure 5. Typical Broadband Circuit Performance

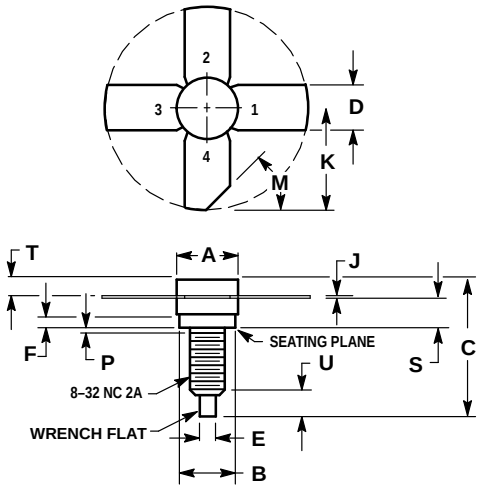


f MHz	Z_{in} Ohms	Z_{OL}* Ohms
440	2.7 + j3.0	2.6 – j0.5
470	2.7 + j3.2	2.6 – j0.1
490	2.7 + j3.6	2.6 + j0.2
512	2.5 + j3.9	2.6 + j0.4

Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 6. Series Equivalent Input and Output Impedance

PACKAGE DIMENSIONS



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	7.06	7.26	0.278	0.286
B	6.20	6.50	0.244	0.256
C	14.99	16.51	0.590	0.650
D	5.46	5.96	0.215	0.235
E	1.40	1.65	0.055	0.065
G	1.52	—	0.060	—
J	0.08	0.17	0.003	0.007
K	11.05	—	0.435	—
M	45° NOM		45° NOM	
P	—	1.27	—	0.050
S	3.00	3.25	0.118	0.128
T	1.40	1.77	0.055	0.070
U	2.92	3.68	0.115	0.145

STYLE 1:
PIN 1. EMITTER
2. BASE
3. EMITTER
4. COLLECTOR

CASE 244–04
ISSUE J

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. “Typical” parameters can and do vary in different applications. All operating parameters, including “Typicals” must be validated for each customer application by customer’s technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and Ⓜ are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

Literature Distribution Centers:
USA: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036.
EUROPE: Motorola Ltd.; European Literature Centre; 88 Tanners Drive, Blakelands, Milton Keynes, MK14 5BP, England.
JAPAN: Nippon Motorola Ltd.; 4-32-1, Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan.
ASIA PACIFIC: Motorola Semiconductors H.K. Ltd.; Silicon Harbour Center, No. 2 Dai King Street, Tai Po Industrial Estate, Tai Po, N.T., Hong Kong.